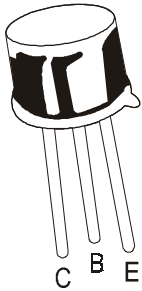


**NPN SILICON PLANAR SWITCHING TRANSISTORS**

**2N2218  
2N2219**



**TO-39  
Metal Can Package**

**2N2218 TO 2N2222 Are NPN Silicon Small Signal General Purpose Amplifier And Switch**

**Switching and Linear Application DC and VHF Amplifier Applications**

**ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)**

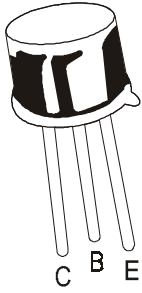
DESCRIPTION	SYMBOL	2N2218, 19	UNIT
Collector Emitter Voltage	$V_{CEO}$	30	V
Collector Base Voltage	$V_{CBO}$	60	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current Continuous	$I_C$	800	mA
Power Dissipation @Ta=25°C	$P_D$	800	mW
Derate Above 25°C		4.57	mW/°C
Power Dissipation @ Tc=25°C	$P_D$	3	W
Derate Above 25°C		17.1	mW/°C
Operating and Storage Junction Temperature Range	$T_j, T_{stg}$	-65 to +200	°C

**ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise )**

DESCRIPTION	SYMBOL	TEST CONDITION	VALUE		UNIT
			MIN	MAX	
Collector Emitter Breakdown Voltage	$BV_{CEO}$	$I_C=10mA, I_B=0$	30		V
Collector Base Breakdown Voltage	$BV_{CBO}$	$I_C=10\mu A, I_E=0$	60		V
Emitter Base Breakdown Voltage	$BV_{EBO}$	$I_E=10\mu A, I_C=0$	5		V
Collector Leakage Current	$I_{CBO}$	$V_{CB}=50V, I_E=0$		10	nA
		$V_{CB}=50V, I_E=0$ $T_a=150^\circ C$		10	$\mu A$
Collector Emitter Saturation Voltage	$V_{CE(Sat)}$ *	$I_C=150mA, I_B=15mA$		0.4	V
		$I_C=500mA, I_B=50mA$		1.6	V
Base Emitter Saturation Voltage	$V_{BE(Sat)}$ *	$I_C=150mA, I_B=15mA$	0.6	1.3	V
		$I_C=500mA, I_B=50mA$		2.6	V

# NPN SILICON PLANAR SWITCHING TRANSISTORS

2N2218  
2N2219



TO-39  
Metal Can Package

## ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	2N2218		2N2219		UNIT
			MIN	MAX	MIN	MAX	
DC Current Gain	$h_{FE}$	$I_C=0.1mA, V_{CE}=10V^*$	20		35		
		$I_C=1mA, V_{CE}=10V$	25		50		
		$I_C=10mA, V_{CE}=10V^*$	35		75		
		$I_C=150mA, V_{CE}=1V^*$	20		50		
		$I_C=150mA, V_{CE}=1V^*$	40	120	100	300	
		$I_C=500mA, V_{CE}=10V^*$	20		30		

## DYNAMIC CHARACTERISTICS

Transition Frequency	$f_T$	$I_C=20mA, V_{CE}=20V$ $f=100MHz$	250		250		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=10V, I_E=0$ $f=100KHz$		8		8	pF
Input Capacitance	$C_{ib}$	$V_{EB}=0.5V, I_C=0$ $f=100kHz$		30		30	pF

## SWITCHING CHARACTERISTICS

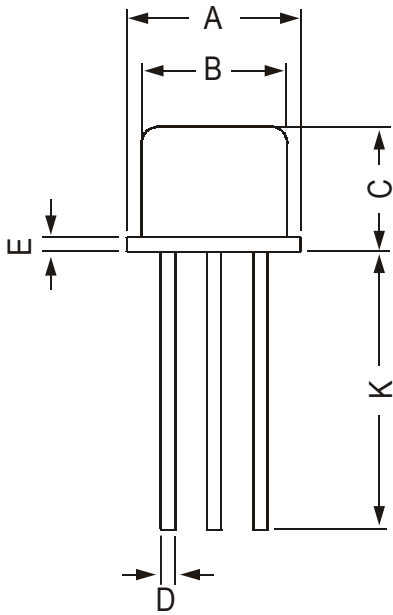
Delay time	$t_d$				10		ns
Rise time	$t_r$	$I_C=150mA, I_{B1}=15mA$				25	ns
Storage time	$t_s$	$V_{CC}=30V, V_{BE(off)}=0.5V$				225	ns
Fall time	$t_f$	$I_C=150mA, I_{B1}=15mA$ $I_{B2}=15mA, V_{CC}=30V$				60	ns

\*Pulse Condition: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$

2N2218  
2N2219

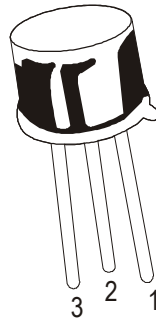
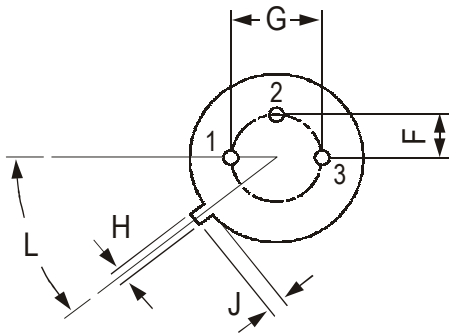
TO-39  
Metal Can Package

TO-39 Metal Can Package



All dimensions are in mm

DIM	MIN	MAX
A	8.50	9.39
B	7.74	8.50
C	6.09	6.60
D	0.40	0.53
E	—	0.88
F	2.41	2.66
G	4.82	5.33
H	0.71	0.86
J	0.73	1.02
K	12.70	—
L	42 DEG	48 DEG



PIN CONFIGURATION

1. EMITTER
2. BASE
3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of

**Continental Device India Limited**

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-2579 6150, 5141 1112 Fax + 91-11-2579 5290, 5141 1119

email@cdil.com www.cdilsemi.com